

#### 20V N-Channel Enhancement Mode MOSFET

Current

#### Features

Voltage

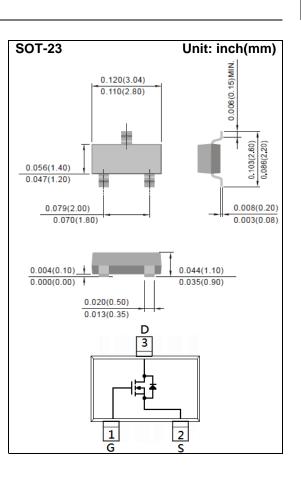
•  $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@4.1A < 56m\Omega$ 

20 V

- $R_{DS(ON)}$ ,  $V_{GS}@2.5V$ ,  $I_D@2.8A{<}68m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@1.8V$ ,  $I_D@1.5A < 95m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 standard

#### **Mechanical Data**

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams



#### Maximum Ratings and Thermal Characteristics (TA=25°C unless otherwise noted)

4.1 A

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	20	v	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 12		
Continuous Drain Current		١D	4.1	A	
Pulsed Drain Current		Ідм	16.4		
Power Dissipation	Ta=25°C		1.25	W	
	Derate above 25°C	PD	10	mW/∘C	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	٥C	
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>		Reja	100	°C/W	



#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	v	
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.4	0.66	1.2	v	
Drain-Source On-State Resistance	$R_{DS(on)}$	V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.1A	-	41	56	mΩ	
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =2.8A	-	50	68		
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =1.5A	-	66	95		
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	-	-	1	uA	
Gate-Source Leakage Current	lgss	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic <sup>(Note 5)</sup>							
Total Gate Charge	Qg		-	4.6	-	nC	
Gate-Source Charge	Qgs	$V_{DS}=10V, I_{D}=4.1A,$	-	0.8	-		
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	1	-		
Input Capacitance	Ciss		-	350	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,	-	40	-		
Reverse Transfer Capacitance	Crss	f=1MHZ	-	29	-		
Turn-On Delay Time	td <sub>(on)</sub>		-	4	-		
Turn-On Rise Time	tr	V <sub>DD</sub> =10V, I <sub>D</sub> =4.1A,	-	47	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=4.5V$ ,	-	18	-		
Turn-Off Fall Time	tf	$R_G=6\Omega^{(Note 1,2)}$	-	10	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	1.5	А	
Diode Forward Voltage	Vsd	Is=1A, V <sub>GS</sub> =0V	-	0.75	1.2	V	

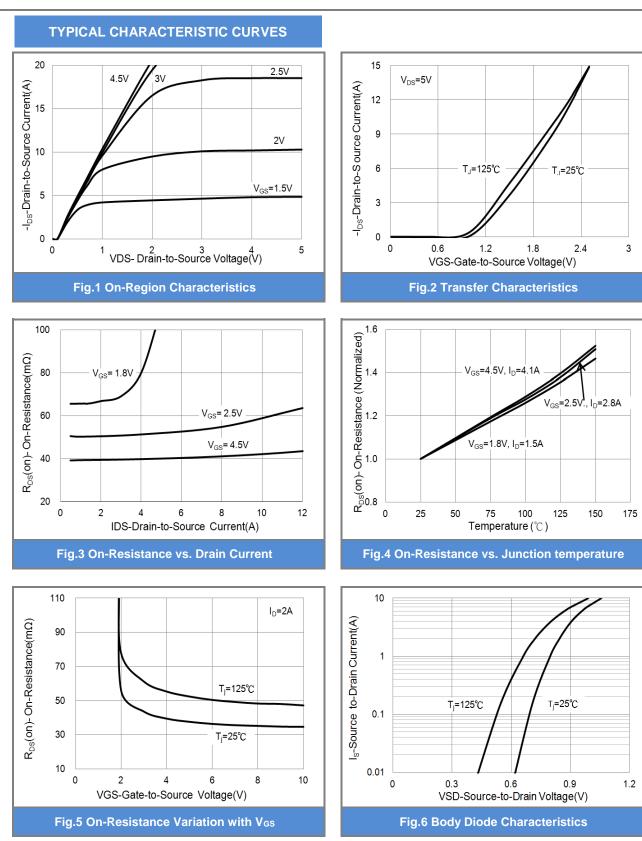
NOTES :

1. Pulse width

2. Essentially independent of operating temperature typical characteristics.

- 3. ReJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.







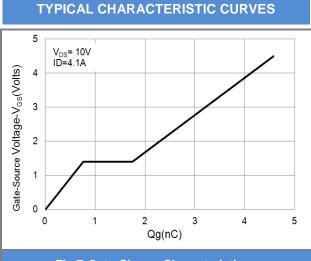


Fig.7 Gate-Charge Characteristics

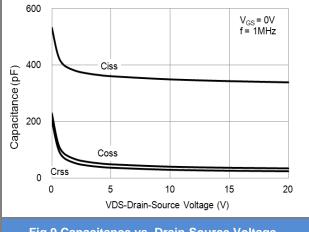
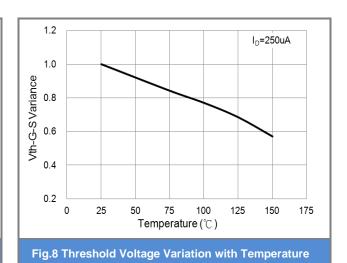


Fig.9 Capacitance vs. Drain-Source Voltage

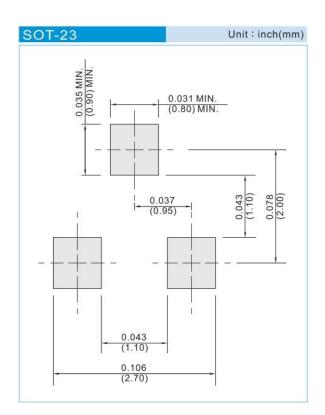




### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJA3412	SOT-23	3K pcs / 7" reel	A12	

#### **Mounting Pad Layout**





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